**Product data sheet** 

## 1. General description

PNP switching transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: BSR14

### 2. Features and benefits

- Single general-purpose switching transistor
- AEC-Q101 qualified

## 3. Applications

Switching and linear amplification

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-60	V
I <sub>C</sub>	collector current		-	-	-600	mA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; $I_{C}$ = -150 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	100	_	300	

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	C
2	Е	emitter		В—
3	С	collector	1 2	E sym132
			TO-236AB (SOT23)	





60V, 600 mA, PNP switching transistor

# 6. Ordering information

### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BSR16	TO-236AB	plastic surface-mounted package; 3 leads	SOT23			

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code [1]
BSR16	Т8%

[1] % = placeholder for manufacturing site code

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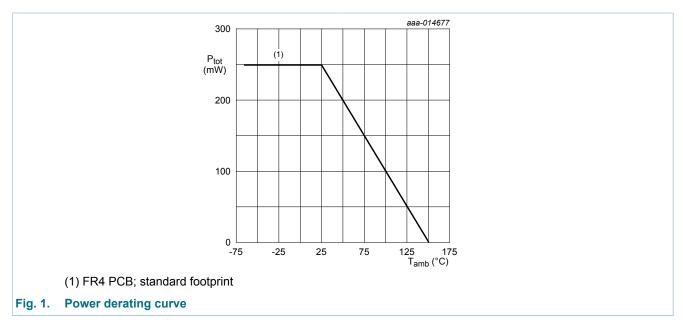
## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter		-	-60	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-60	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-600	mA
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-800	mA
I <sub>BM</sub>	peak base current			-	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	250	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Transistor mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



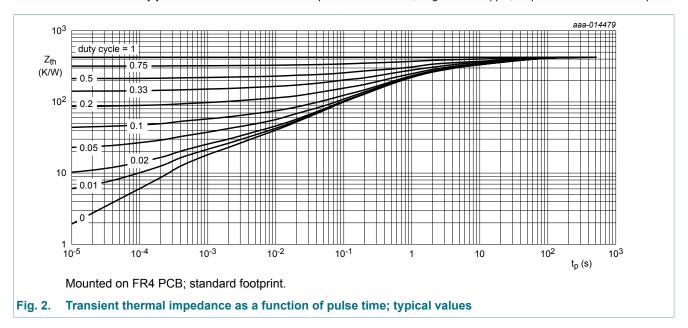
## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	_	500	K/W
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[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.



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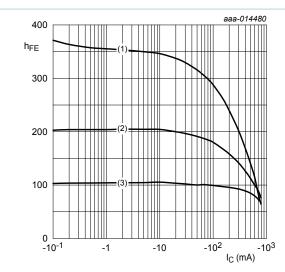
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## 10. Characteristics

### Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB}$ = -50 V; $I_{E}$ = 0 A; $T_{amb}$ = 25 °C	-	-	-10	nA
	current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	-	-10	μA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -5 V; I <sub>C</sub> = 0 A; T <sub>amb</sub> = 25 °C	-	-	-50	nA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = -10 V; $I_{C}$ = -0.1 mA; $T_{amb}$ = 25 °C	75	-	-	
		$V_{CE}$ = -10 V; $I_{C}$ = -1 mA; $T_{amb}$ = 25 °C	100	-	-	
		$V_{CE}$ = -10 V; $I_{C}$ = -10 mA; $T_{amb}$ = 25 °C	100	-	-	
		$V_{CE}$ = -10 V; $I_{C}$ = -150 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb}$ = 25 °C	100	-	300	
		$V_{CE}$ = -10 V; $I_{C}$ = -500 mA; pulsed; $t_{p} \le 300 \ \mu s; \ \delta \le 0.02; \ T_{amb} = 25 \ ^{\circ}C$	50	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C}$ = -150 mA; $I_{B}$ = -15 mA; $T_{amb}$ = 25 °C	-	-	-400	mV
		$I_C$ = -500 mA; $I_B$ = -50 mA; $T_{amb}$ = 25 °C	-	-	-1.6	V
V <sub>BEsat</sub>	base-emitter saturation voltage	$I_C$ = -150 mA; $I_B$ = -15 mA; $T_{amb}$ = 25 °C	-	-	-1.3	V
		$I_C$ = -500 mA; $I_B$ = -50 mA; $T_{amb}$ = 25 °C	-	-	-2.6	V
t <sub>d</sub>	delay time	I <sub>C</sub> = -150 mA; I <sub>Bon</sub> = -15 mA;	-	-	12	ns
t <sub>r</sub>	rise time	I <sub>Boff</sub> = 15 mA; T <sub>amb</sub> = 25 °C	-	-	30	ns
t <sub>on</sub>	turn-on time		-	-	40	ns
t <sub>s</sub>	storage time		-	-	300	ns
t <sub>f</sub>	fall time		-	-	65	ns
t <sub>off</sub>	turn-off time		-	-	365	ns
C <sub>C</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	8	pF
C <sub>E</sub>	emitter capacitance	$V_{EB}$ = -2 V; $I_{C}$ = 0 A; $i_{c}$ = 0 A; f = 1 MHz; $T_{amb}$ = 25 °C	-	-	30	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -20 V; $I_{C}$ = -50 mA; f = 100 MHz; $T_{amb}$ = 25 °C	200	-	-	MHz

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$$V_{CE}$$
 = -10  $V$ 

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55$$
 °C

Fig. 3. DC current gain as a function of collector current; typical values

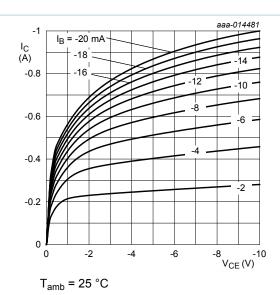
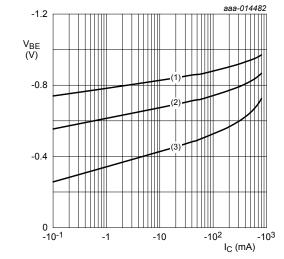


Fig. 4. Collector current as a function of collectoremitter voltage; typical values



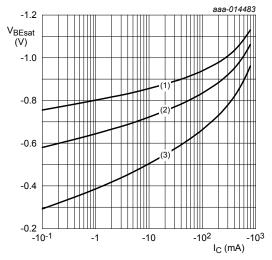
$$V_{CE} = -10 \text{ V}$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 5. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

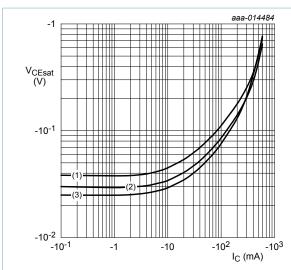
(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values

### 60V, 600 mA, PNP switching transistor



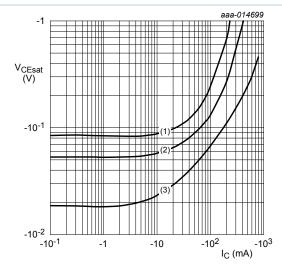
$$I_{\rm C}/I_{\rm B}=20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb}$$
 = 25 °C

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



$$T_{amb}$$
 = 25 °C

(1) 
$$I_C/I_B = 100$$

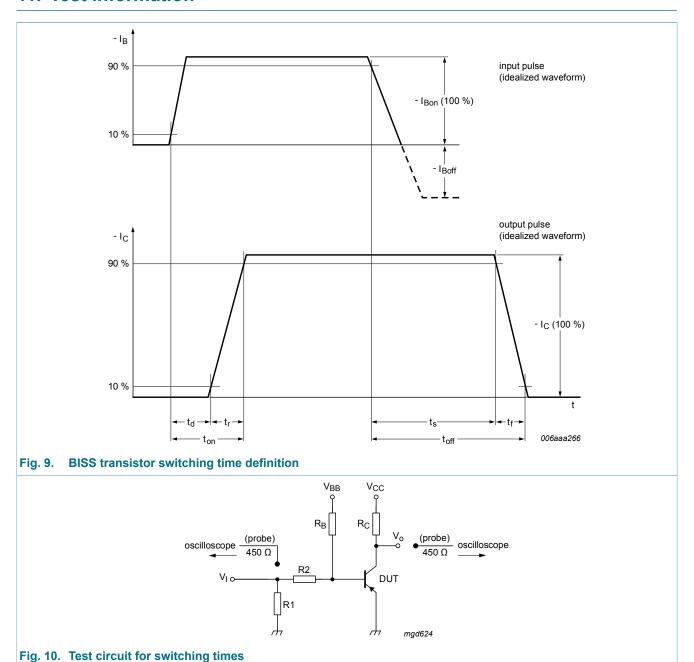
(2) 
$$I_C/I_B = 50$$

(3) 
$$I_C/I_B = 10$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

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## 11. Test information

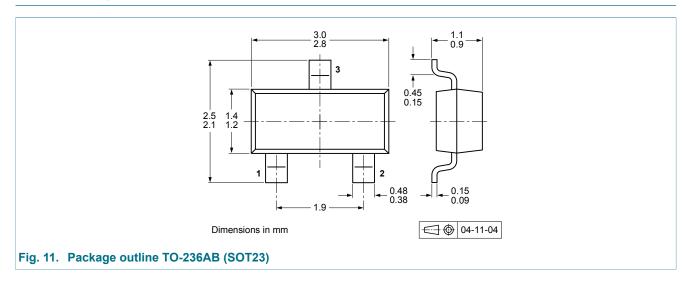


## 11.1 Quality information

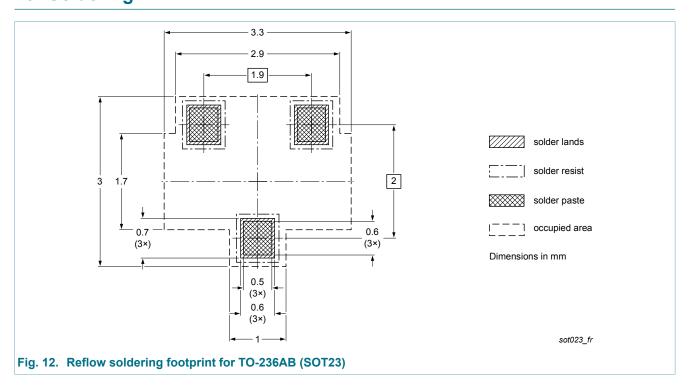
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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## 12. Package outline

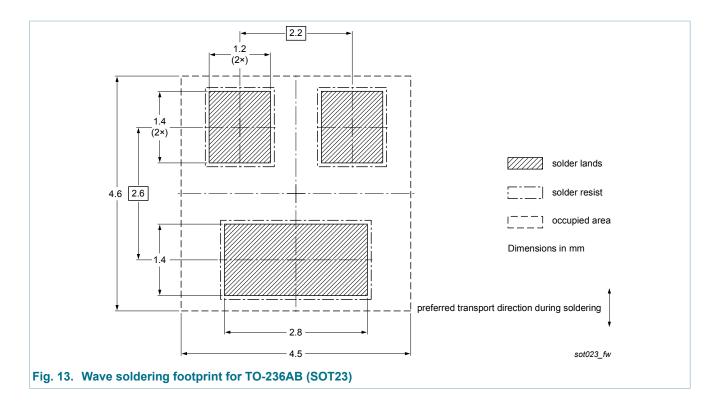


## 13. Soldering



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# 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
BSR16 v.5	20150424	Product data sheet	-	BSR15; BSR16 v.4				
Modifications:	<ul> <li>Type BSR15 removed</li> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors</li> <li>Legal texts have been adapted to the new company name where appropriate</li> </ul>							
BSR15; BSR16 v.4	20040113	Product data sheet	-	BSR15; BSR16 v.3				
BSR15; BSR16 v.3	19990415	Product data sheet	-	-				

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#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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